



# **RF Switch Series – RoHS Compliance**

## **DPDT GPIO Switch**

## **Halogens Free Product**

Any 2G/3G/4G Band for TRx System

## P/N: RFASWB643ATF09

\*Contents in this sheet are subject to change without prior notice.

## Approval Sheet FEATURES



- Low Insertion Loss : 0.45dB typ. @ 2.7GHz
- High Isolation : 27dB typ. @ 2.7GHz
- Low control voltage : 1.3 to 2.7 V
- Miniature footprint : 2.0 x 2.0 x 0.55 mm<sup>3</sup>
- <u>Moisture</u> <u>Sensitive</u> <u>Level</u> 3 (MSL3)
- High ESD tolerance of 2kV HBM at all pins

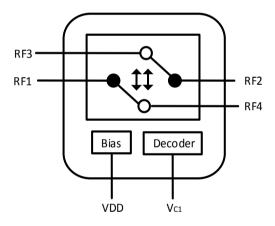
#### Description

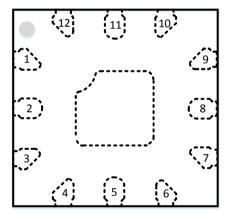
- The RFASWB643ATF09 is a SOI (Silicon On Insulator) double pole double throw (DPDT) switch in a low cost miniature QFN (2.0x2.0 x0.55mm<sup>3</sup>) package. Typical applications are for SV-LTE ,LTE-A and diversity antenna switching.
- The RFASWB643ATF09 is ideally suited for applications where high power, high linearity, low insertion loss, and small size are required.
- The RFASWB643ATF09 has ESD protection devices to achieve excellent ESD performances.

#### **Application**

■ 2G/3G/4G multimode cellular handsets (LTE, UMTS, CDMA2000, EDGE, GSM, TDD-LTE, TD-SCDMA)

### Block Diagram and Pin Out (Top View)

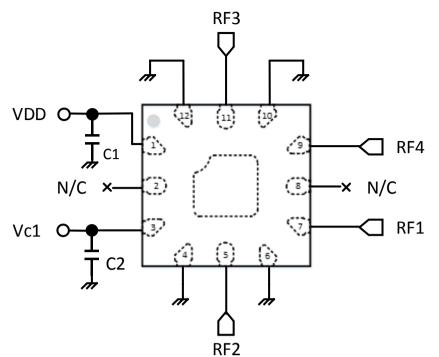




#### **Pin Names and Descriptions**

Pin	Name	Description	Pin	Name	Description
1	VDD	DC power supply	7	RF1	RF path 1
2	N/C	No connected	8	N/C	No connected
3	V <sub>C1</sub>	Control voltage 1	9	RF4	RF path 4
4	GND	Ground	10	GND	Ground
5	RF2	RF path 2	11	path3	RF path 3
6	GND	Ground	12	GND	Ground

**Application Circuit** 



#### Parts List

Parts No.	Value		
C1-C2	1000 pF		

### **Absolute Maximum Ratings**

Parameter		Minimum	Maximum	Units
Max Input Power	Pin		+36	dBm
DC Supply Voltage	VDD	+2.6	+5.0	V
DC Control Voltage	V <sub>C1</sub>	0	+2.7	V
Operating temperature	Тор	-30	+85	°C
Storage temperature	T <sub>ST</sub>	-65	+105	°C
HBM ESD Voltage, All Pins	V <sub>ESD</sub> <sup>1</sup>	-	+2000	V

Exceeding absolute maximum ratings may cause permanent damage. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

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## **Approval Sheet**



Electrical Specifications at 25°C with VDD=2.8V, V<sub>C1</sub>=0/1.8V, Characteristic Impedance Z<sub>0</sub>=50Ω, Pin=0dBm

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Units	
RF Specifications							
Operating frequency	f		0.7		3.0	GHz	
Insertion loss (Port1/2 to Port3/4)	IL	0.7 ~ 1.0 GHz 1.0 ~ 2.0 GHz 2.0 ~ 2.7 GHz		0.30 0.35 0.45	0.40 0.50 0.60	dB dB dB	
Isolation (Port1/2 to Port3/4)	lso	0.7 ~ 1.0 GHz 1.0 ~ 2.0 GHz 2.0 ~ 2.7 GHz	32 26 22	40 32 27	- - -	dB dB dB	
On state match (Port1/2) VSV		0.7 ~ 2.7 GHz	-	1.12	1.5	-	
	2f <sub>0</sub>	PIN = +36 dBm, f = 900 MHz	-	-72	-70	dBc	
RFx Harmonics	3f <sub>0</sub>	PIN = +36 dBm, f = 900 MHz	-	-73	-60	dBc	
3 <sup>rd</sup> Order Intermodulation Distortion	IMD3	F <sub>cw1</sub> =1.85 GHz, P <sub>cw1</sub> = +20dBm F <sub>cw2</sub> =1.74 GHz, P <sub>cw2</sub> = -15dBm	-	-115	-	dBm	
2 <sup>nd</sup> Order Input Intercept Point	IIP2	F <sub>cw1</sub> =0.9 GHz, P <sub>cw1</sub> = +20dBm F <sub>cw1</sub> =1.85 GHz, P <sub>cw2</sub> = 0dBm	-	+115	-	dBm	
DC Specification (Decoder)							
Supply Voltage	VDD		2.6	2.8	4.5	V	
Supply Current	IDD	VDD= 2.8V	-	70	-	μA	
Control Voltage(High)	V <sub>C1(H)</sub>		1.3	1.8	2.7	V	
Control Voltage(Low)	V <sub>C1(L)</sub>		0	-	0.45	V	
Control Current	I <sub>C1</sub>	V <sub>C1</sub> = 1.8V	-	0.1	5	μA	
Switching Specification		•	·				
Switching speed Tsw		50% V <sub>CTL</sub> to 90/10% RF	-	-	5	μs	

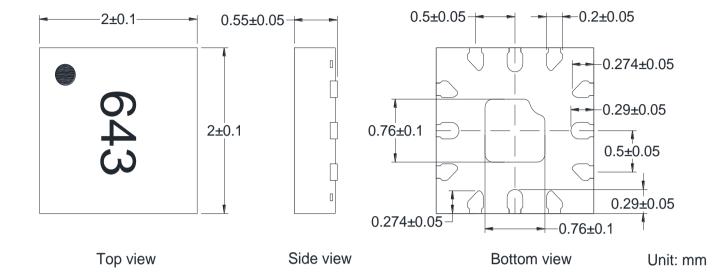
Note : All measurements made in a 50Ω system with 0/+1.8V control voltages, unless otherwise specified.

## Logic Table for Switch On-Path

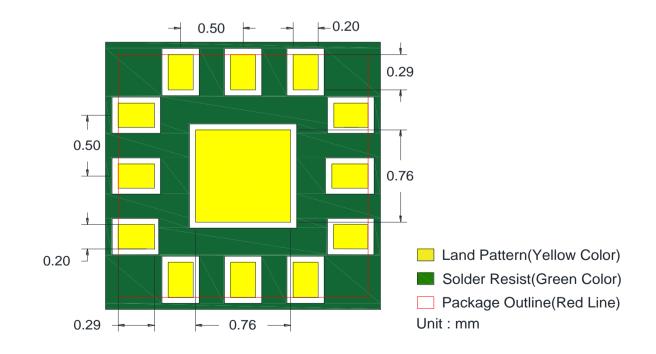
VC1	State			
1	PORT3 to PORT1, PORT4 to PORT2			
0	PORT3 to PORT2, PORT4 to PORT1			

State 1=1.3V to 2.7V ; State 0= 0V to 0.45V





Solder Land Pattern





## Approval Sheet Reliability test

TEST	PROCEDURE / TEST METHOD	REQUIREMENT
Solderability	*Solder bath temperature : $255 \pm 5^{\circ}C$	At least 95% of a surface of each terminal
JIS C 0050-4.6	*Immersion time:5 $\pm$ 0.5 sec	electrode must be covered by fresh solder.
JESD22-B102D	Solder : Sn3Ag0.5Cu for lead-free	
High temperature	*Temperature: 90°C±2°C	No mechanical damage.
JIS C 0021	*Test duration : 1000+24/-0 hours	Electrical specification shall satisfy the
	Measurement to be made after keeping at room	descriptions in electrical characteristics under
	temperature for 24±2 hrs	the operational temperature range within -30 $$ ~
		90°C.
Low temperature	*Temperature:-30°C±2°C	No mechanical damage.
JIS C 0020	*Test duration : 1000+24/-0 hours	Electrical specification shall satisfy the
	Measurement to be made after keeping at room	descriptions in electrical characteristics under
	temperature for 24±2 hrs	the operational temperature range within -30 $$ ~
		90°C.
Temperature cycle	1. 30±3 minutes at -30±3°C,	No mechanical damage.
JIS C 0025	2. 10~15 minutes at room temperature,	Electrical specification shall satisfy the
	3. 30±3 minutes at +90±3°C,	descriptions in electrical characteristics under
	4. 10~15 minutes at room temperature,	the operational temperature range within -30 $$ ~
	Total 100 continuous cycles	90°C.
	Measurement to be made after keeping at room	
	temperature for 24±2 hrs	
High temperature operation	*Temperature : 90°C	No mechanical damage.
life (HTOL)	*VDD = 4.8V	Electrical specification shall satisfy the
	*Time:1000+24/-0 hrs.	descriptions in electrical characteristics under
	Measurement to be made after keeping at room	the operational temperature range within -30 $$ ~
	temperature for 24±2 hrs	90°C.

## **Soldering condition**

Typical examples of soldering processes that provide reliable joints without any damage are given in Figure 11.

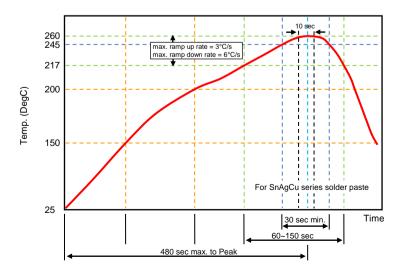


Figure 11. Infrared soldering profile



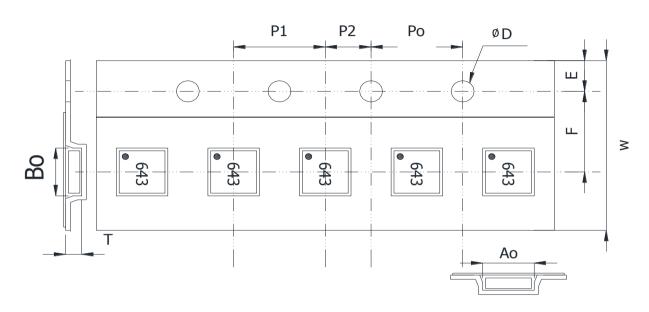
## **Approval Sheet**

## Ordering code

RF	ASW	ASW B		Т
RF module	Module type	Application	Design Code	Packing
RF:	ASW: Antenna Switch	B: DPDT		T: Taping
Walsin RF Switch				
Device				

Minimum Ordering Quantity: 3000 pcs per reel.

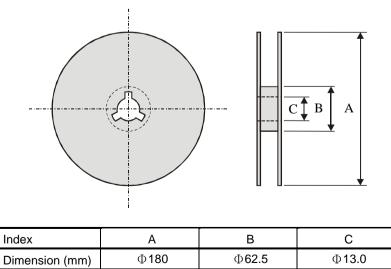
## Packaging



## Plastic Tape specifications (unit :mm)

Index	Ao	Во	ΦD	Т	W
Dimension (mm)	$\textbf{2.25} \pm \textbf{0.10}$	$\textbf{2.25} \pm \textbf{0.10}$	$1.55\pm0.05$	$\textbf{0.75} \pm \textbf{0.10}$	$8.00\pm0.3$
Index	E	F	Po	P1	P2
Dimension (mm)	$1.75\pm0.10$	$\textbf{3.50}\pm\textbf{0.10}$	$4.00\pm0.10$	$4.00\pm0.10$	$2.00\pm0.05$

#### **Reel dimensions**



Taping Quantity : 3000 pieces per 7" reel

## **Approval Sheet**



#### **Caution of handling**

#### Limitation of Applications

Please contact us before using our products for the applications listed below which require especially high reliability for the prevention of defects, which might directly cause damage to the third party's life, body or property.

- (1) Aircraft equipment
- (2) Aerospace equipment
- (3) Undersea equipment
- (4) Medical equipment
- (5) Disaster prevention / crime prevention equipment
- (6) Traffic signal equipment
- (7) Transportation equipment (vehicles, trains, ships, etc.)
- (8) Applications of similar complexity and /or reliability requirements to the applications listed in the above.

#### **Storage condition**

- (1) Products should be used in 6 months from the day of WALSIN outgoing inspection, which can be confirmed.
- (2) Storage environment condition.
  - Products should be storage in the warehouse on the following conditions.
  - Temperature : -10 to +40°C
    - Humidity : 30 to 70% relative humidity
  - Don't keep products in corrosive gases such as sulfur. Chlorine gas or acid or it may cause oxidization of electrode, resulting in poor solderability.
  - Products should be storage on the palette for the prevention of the influence from humidity, dust and son on.
  - Products should be storage in the warehouse without heat shock, vibration, direct sunlight and so on.
  - Products should be storage under the airtight packaged condition.



单击下面可查看定价,库存,交付和生命周期等信息

>>Walsin Technology(华新科技(华科))